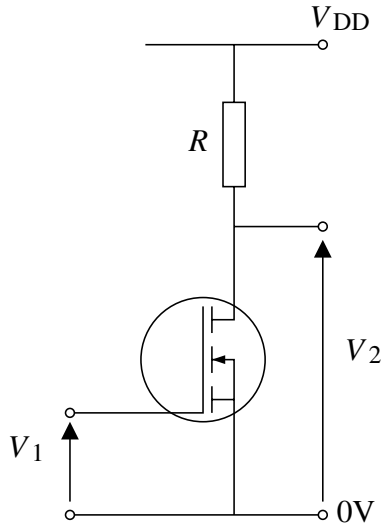


COMPUTER SCIENCE TRIPOS Part IA – 2021 – Paper 2

2 Digital Electronics (ijw24)

The figure below shows a circuit using an N-channel MOSFET, along with a table giving the relationship between V_{DS} and I_{DS} for various values of V_{DS} , at $V_{DD} = 4\text{ V}$ and $V_{GS} = 4\text{ V}$.

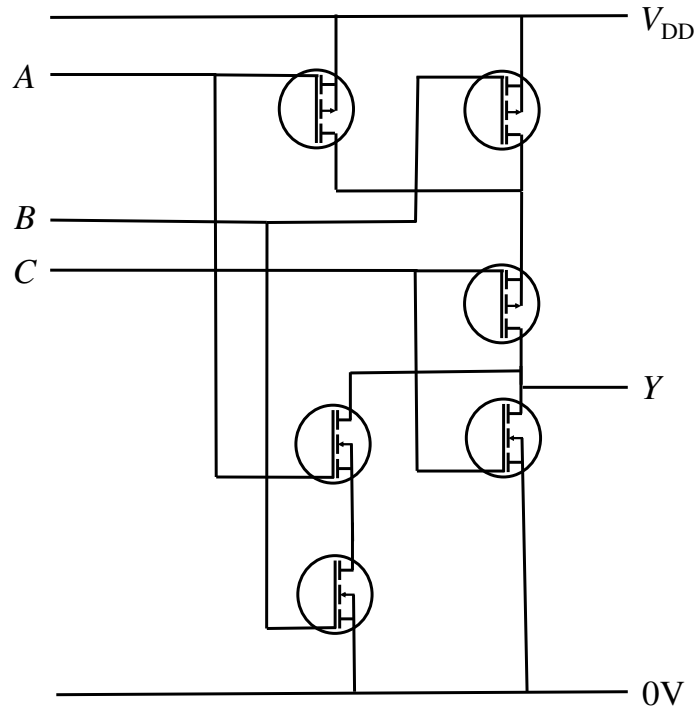


$V_{DS}(\text{mV})$	160	320	470
$I_{DS}(\text{mA})$	48	92	130

- (a) Calculate the value of resistor R and the power dissipated in it when $V_{DS} = 160\text{ mV}$. [4 marks]
- (b) A capacitor C is connected between the source and drain terminals of the MOSFET. After the MOSFET turns OFF at $t = 0$, the output signal V_2 as a function of time t is given by $V_2 = V_{DD}(1 - e^{-t/CR})$. Assume that prior to $t = 0$, the MOSFET is ON and $V_2 = 0\text{ V}$.
- (i) Determine an expression for the time taken t_r , for the output signal V_2 to rise from 20% to 80% of its maximum value.
- (ii) What is the rise time t_r , if $C = 0.1\ \mu\text{F}$ and R takes the value calculated in Part (a)?
- (iii) The value of R is changed so as to reduce the rise time to half that in Part (b)(ii). What is the new value of R ?
- (iv) Using the value of R calculated in Part (b)(iii), what is the power dissipated in R when the MOSFET is ON (i.e., when $V_{GS} = 4\text{ V}$), and assuming that $V_2 = 320\text{ mV}$?
- (v) Explain how the problem of high static power consumption seen in the N-channel MOSFET circuit can be eliminated. [9 marks]

[continued ...]

- (c) The logic gate in the following figure has 3 inputs, A , B , and C , and a single output Y . Determine the truth-table for the gate input to output function, and then determine a simplified Boolean expression for output Y in terms of A , B , and C .



[7 marks]